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# 4-Bit Dual-Supply Bus Buffer Level Translator with 26 $\Omega$ Output Series Resistor

The NLSV4T3234 is a 4-bit configurable dual-supply voltage level translator. The input (B–) and output (A–) ports are designed to track two different power supply rails,  $V_{CCB}$  and  $V_{CCA}$  respectively. Both supply rails are configurable from 0.9 V to 4.5 V, allowing high–to–low and low–to high voltage translation from the input (B–) to the output (A–) port.

The NLSV4T3234 is a low power voltage translator that contains series output resistors, and overvoltage tolerant (OVT) input and output protection. The 26  $\Omega$  series resistor on the output drivers minimizes ringing on the logic transition edges. The OVT feature allows the NLSV4T3234 to translate input signals greater than the input power supply  $V_{CCB}$  and protects the IC from damage if a signal is connected to an output pin that is greater than  $V_{CCA}$ .

#### **Features**

- Wide V<sub>CCA</sub> and V<sub>CCB</sub> Operating Range: 0.9 V to 4.5 V
- High-Speed Logic Voltage Translation
- 26  $\Omega$  Series Resistors on Outputs (A–) Reduce Ground Bounce and Overshoot
- Overvoltage Tolerant (OVT) Inputs and Outputs to 4.5 V
- Non-preferential Power Supply Sequencing
- Outputs At 3-State Until Active V<sub>CC</sub> Is Reached
- Outputs Switch to 3-State with V<sub>CCA</sub> at GND
- Ultra-Small Packaging: 1.41 mm x 2.04 mm Flip-Chip11
- RoHS Compliant
- This is a Pb–Free Device\*

#### **Typical Applications**

• Mobile Phones, PDAs, Other Portable Devices

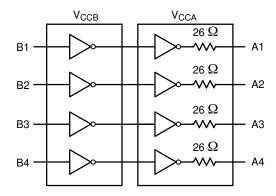


Figure 1. Logic Diagram



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#### MARKING DIAGRAM



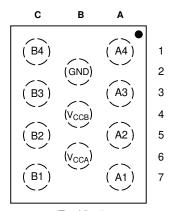
11 PIN FLIP-CHIP FC SUFFIX CASE 766AJ



4T3234 = Specific Device Code A = Assembly Location

Y = Year WW = Work Week = Pb-Free Package

#### **PIN ASSIGNMENT**



(Top View)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLSV4T3234FCT1G	Flip-Chip11 (Pb-Free)	3000/ Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PIN NAMES**

PIN	Description
V <sub>CCB</sub>	Input Port DC Power Supply
V <sub>CCA</sub>	Output Port DC Power Supply
GND	Ground
B <sub>n</sub>	Input Port
An	Output Port

#### **TRUTH TABLE**

Inputs (B <sub>n)</sub>	Outputs (A <sub>n</sub> )
L	L
Н	Н

#### **PIN DESCRIPTION**

Pin	Symbol	Description
A1	A4	Data Output
А3	A3	Data Output
A5	A2	Data Output
A7	A1	Data Output
B2	GND	Ground
В4	V <sub>CCB</sub>	Input Power Supply
B6	V <sub>CCA</sub>	Output Power Supply
C1	B4	Data Input
C3	B3	Data Input
C5	B2	Data Input
C7	B1	Data Input

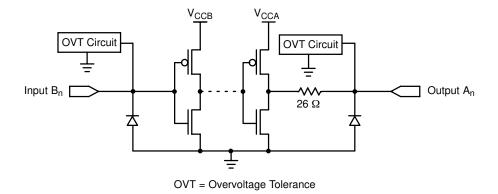


Figure 2. Simplified Input and Output Circuit Schematic

#### **MAXIMUM RATINGS**

Symbol	Ratir	ng		Value	Condition	Unit
V <sub>CCA</sub> , V <sub>CCB</sub>	DC Supply Voltage			-0.5 to +5.5		V
VI	DC Input Voltage	(Power Down)	B <sub>n</sub>	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
		(Active Mode)	B <sub>n</sub>	-0.5 to +5.5		
V <sub>O</sub>	DC Output Voltage	(Power Down)	A <sub>n</sub>	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
		(Active Mode)	A <sub>n</sub>	-0.5 to +5.5		V
I <sub>IK</sub>	DC Input Diode Current			-20		mA
I <sub>OK</sub>	DC Output Diode Current			-50	$V_O > V_{CC}$ ; $V_O < GND$	mA
Io	DC Output Source/Sink C	urrent		±50		mA
I <sub>CCA</sub> , I <sub>CCB</sub>	DC Supply Current Per St	upply Pin		±100		mA
I <sub>GND</sub>	DC Ground Current per G	round Pin		±100		mA
T <sub>STG</sub>	Storage Temperature			-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Parameter						
V <sub>CCA</sub> , V <sub>CCB</sub>	Positive DC Supply Voltage		0.9	4.5	V			
$V_{IB}$	Bus Input Voltage (B <sub>n)</sub>		GND	4.5	V			
$V_{IA}$	Bus Output Voltage (An)	(Power Down Mode)	GND	4.5	V			
		(Active Mode)	GND	V <sub>CCA</sub>	V			
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C			
$\Delta t / \Delta V$	Input Transition Rise or Rate (Note 1)	V <sub>CCB</sub> = 3.6 to 4.5 V	0	10	nS/V			
		$V_{CCB} = 2.3 \text{ to } 3.5 \text{ V}$	0	20	nS/V			
		$V_{CCB} = 0.9 \text{ to } 2.2 \text{ V}$	0	100	nS/V			

<sup>1.</sup>  $V_I$  from 0.8 V to 2.0 V at  $V_{CC} = 3.0 \text{ V}$ 

#### DC ELECTRICAL CHARACTERISTICS

					-40°C t	o +85°C			
Symbol	Parameter	V <sub>CCB</sub> (V)	V <sub>CCA</sub> (V)	Test Conditions	Min	Max	Unit		
		3.6 – 4.5			2.3	-			
		2.7 – 3.6			2.0	-			
$V_{IHB}$	HB Input HIGH Voltage	2.3 – 2.7	0.9 – 4.5		1.6	-	٧		
		1.4 –2.3	1.4 –2.3		0.65 * V <sub>CCB</sub>	-			
		0.9 – 1.4			0.9 * V <sub>CCB</sub>	-			
		3.6 – 4.5			-	0.8			
		2.7 – 3.6			-	0.8			
$V_{ILB}$	Input LOW Voltage	2.3 – 2.7	0.9 – 4.5		-	0.7	٧		
		1.4 –2.3			-	0.35 * V <sub>CCB</sub>			
		0.9 – 1.4			-	0.1 * V <sub>CCB</sub>			
			0.9 – 4.5	$I_{OH} = -100 \mu A; V_I = V_{IH}$	V <sub>CCA</sub> - 0.2	-			
			0.9	$I_{OH} = -0.5 \text{ mA}; V_I = V_{IH}$	0.75 * V <sub>CCA</sub>	-			
			1.4	$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.05	-			
			1.65	$I_{OH} = -6 \text{ mA}; V_I = V_{IH}$	1.25	-	V		
			2.3		2.0	-			
$V_{OHA}$	Output HIGH Voltage	0.9 - 4.5	2.3		1.8	_			
			2.7	$I_{OH} = -12 \text{ mA}; V_I = V_{IH}$	2.2	_			
			2.3		1.7	-			
			3.0	$I_{OH} = -18 \text{ mA}; V_I = V_{IH}$	2.4	-			
			3.0	$I_{OH} = -24 \text{ mA}; V_I = V_{IH}$	2.2	-			
			0.9 – 4.5	$I_{OL} = 100 \mu A; V_I = V_{IL}$	-	0.2			
			1.1	$I_{OL} = 0.5 \text{ mA}; V_I = V_{IH}$	-	0.3 * V <sub>CCA</sub>			
			1.4	$I_{OL} = 2 \text{ mA}; V_I = V_{IH}$	-	0.35			
			1.65	$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	-	0.3			
$V_{OLA}$	Output LOW Voltage	Output LOW Voltage	Output LOW Voltage	0.9 – 4.5	2.3		-	0.4	٧
			2.7	$I_{OL} = 12 \text{ mA}; V_I = V_{IL}$	-	0.4			
			2.3		-	0.6			
	3.0	3.0	$I_{OL} = 18 \text{ mA}; V_I = V_{IL}$	-	0.4				
			3.0	I <sub>OL</sub> = 24 mA; V <sub>I</sub> = V <sub>IL</sub>	-	0.55			
II	Input Leakage Current	0.9 – 4.5	0.9 – 4.5	V <sub>I</sub> = V <sub>CCB</sub> or GND	-	±1.0	μΑ		
I <sub>OFF</sub>	Power-Off Leakage Current	0	0	$V_{I}$ or $V_{O} = 0$ to 4.5 V	-	±3.0	μΑ		
I <sub>CCA</sub> , I <sub>CCB</sub>	Quiescent Supply Current	0.9 – 4.5	0.9 – 4.5	$V_I = V_{CCB}$ or GND; $I_O = 0$	-	±1.5	μΑ		
CCA + ICCB	Quiescent Supply Current	0.9 – 4.5	0.9 – 4.5	$V_I = V_{CCB}$ or GND; $I_O = 0$	-	±3.0	μΑ		
$\Delta I_{CCB}$	Increase in $I_{CC}$ per Input Voltage, Other Inputs at $V_{CC}$ or GND	4.5	4.5	$V_I = V_{CCB} - 0.6 \text{ V};$ $V_I = V_{CCB} \text{ or GND}$	-	500.0	μΑ		

#### **AC ELECTRICAL CHARACTERISTICS**

							–40°C t	o +85°C					
							V <sub>CC</sub>	<sub>A</sub> (V)					
			1	.5	1	.8	2	.8	3	.3	4	.5	
Symbol	Parameter	V <sub>CCB</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
	Propagation Daloy	1.5	-	5.2	-	4.5	-	3.9	-	3.8	-	3.7	
	Propagation Delay	1.8	_	4.9	-	4.3	-	3.8	-	3.4	-	3.5	20
t <sub>PLH</sub> , t <sub>PHL</sub>	B <sub>n</sub> to A <sub>n</sub>	2.8	-	4.7	-	4.2	-	3.4	-	3.3	-	3.2	nS
4PHL	$(C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega) \text{ (Note 2)}$	3.3	-	4.6	-	4.0	-	3.4	-	3.3	-	3.1	
	11[ - 2 KS2) (NOTE 2)	4.5	-	4.6	-	4.0	_	3.5	_	3.3	-	3.1	
		1.5	-	5.6	-	4.8	-	4.2	-	4.2	-	4.5	nS
	Propagation Delay	1.8	-	5.4	-	4.6	-	3.9	-	3.9	-	3.8	
t <sub>PLH</sub> , t <sub>PHL</sub>	B <sub>n</sub> to A <sub>n</sub>	2.8	-	5.2	-	4.4	-	3.7	-	3.7	-	3.3	
*FFIL		3.3	-	5.1	-	4.1	_	3.6	-	3.6	-	3.2	
	$(C_L = 30 \text{ pF}, R_L = 2 \text{ k}\Omega) \text{ (Note 2)}$	4.5	-	5.1	-	3.8	-	3.1	-	3.0	-	3.0	
		1.5	-	0.2	-	0.2	_	0.2	_	0.2	-	0.2	nS
		1.8	-	0.2	-	0.2	-	0.2	-	0.2	-	0.2	
tostH,	Output to Output Skew Time	2.8	-	0.2	-	0.2	-	0.2	-	0.2	-	0.2	1
toshl	(Notes 3 & 4)	3.3	-	0.2	-	0.2	-	0.2	-	0.2	-	0.2	1
		4.5	-	0.2	-	0.2	-	0.2	-	0.2	-	0.2	

#### **DYNAMIC SWITCHING CHARACTERISTICS**

			T <sub>A</sub> = 25 °			
Symbol	Parameter	V <sub>CCB</sub> (V)	V <sub>CCA</sub> (V)	Test Conditions	Тур	Unit
V <sub>OLPA</sub>	Dynamic Low Level Quiet An	1.8	1.8	C <sub>L</sub> = 30 pF	0.1	V
	Output (overshoot)	2.8	2.8	$V_{IL} = 0V$ $V_{IH} = V_{CCB}$	0.25	
		3.6	3.6	VIH = VCCB	0.35	
V <sub>OLVA</sub>	Dynamic Low Level Quiet An	1.8	1.8	C <sub>L</sub> = 30 pF	-0.1	V
	Output (ground bounce)	2.8	2.8	$V_{IL} = 0V$ $V_{IH} = V_{CCB}$	-0.25	
		3.6	3.6	VIH = VCCB	-0.35	
V <sub>OHVA</sub>	Dynamic Low Level Quiet An	1.8	1.8	C <sub>L</sub> = 30 pF	1.6	V
	Output	2.8	2.8	$V_{IL} = 0V$ $V_{IH} = V_{CCB}$	2.6	
		3.6	3.6	™ - VCCB	3.3	

#### **CAPACITANCE**

Symbol	Parameter	Test Conditions	Typ (Note 5)	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCB}$	3.5	pF
C <sub>O</sub>	Output Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCB}$	5.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	$V_{CCA} = V_{CCB} = 1.8$ , 2.8 or 3.6 V, $V_I = 0$ V or $V_{CCB}$ , $f = 1$ MHz	28	pF

Propagation delays defined per Figure 3.
 Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW (toslh = | tplhm - tplhn |, toshl = | tphhm - tphhn |).

<sup>4.</sup> Parameter guaranteed by design.

<sup>5.</sup> Typical values are at T<sub>A</sub> = +25°C
6. C<sub>PD</sub> is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I<sub>CC(operating)</sub> = C<sub>PD</sub> x V<sub>CC</sub> x f<sub>IN</sub> + I<sub>CC</sub>/4 (per circuit).

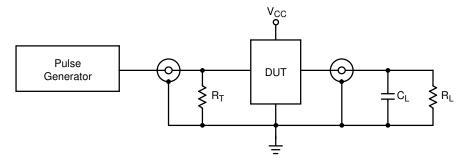


Figure 3. AC (Propagation Delay) Test Circuit

Test
t <sub>PLH</sub> , t <sub>PHL</sub> , t <sub>OSLH</sub> , t <sub>OSHL</sub>
$C_L$ = 15 pF / 30 pF or equivalent (includes probe and jig capacitance) $R_L$ = 2 k $\Omega$ or equivalent $Z_{OUT}$ of pulse generator = 50 $\Omega$ $R_T$ = 50 $\Omega$

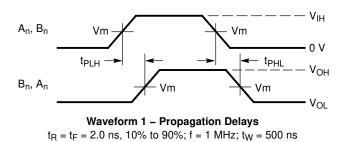
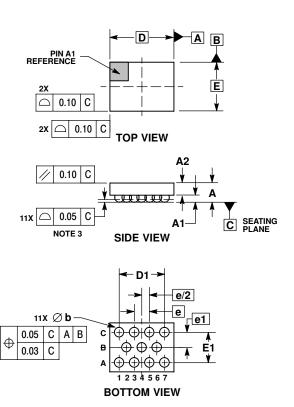


Figure 4. AC Waveforms

	V <sub>CC</sub>
Symbol	1.5 V, 1.8 V, 2.8 V, 3.3 V, 4.5 V
V <sub>mA</sub>	V <sub>CCA</sub> /2
V <sub>mB</sub>	V <sub>CCB</sub> /2

#### PACKAGE DIMENSIONS

11 PIN FLIP-CHIP, 2.04x1.41, 0.5P CASE 766AJ-01 **ISSUE O** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

	MILLIMETERS	
DIM	MIN	MAX
Α		0.66
A1	0.21	0.27
A2	0.33	0.39
b	0.29	0.34
D	2.04 BSC	
D1	1.50 BSC	
Е	1.41	BSC
E1	0.86	BSC
е	0.50	BSC
e1	0.43	BSC

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